

SPEC SHEET (FOR REFERENCE)	SHEET No.	Rev.	Page.
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TYPE : 6PT2706N4D**

CHIP SIZE	0.28 * 0.28 mm
WAFER SIZE	6 inch
POSSIBLE DIE PER WAFER	190,894 pcs

Maximum Ratings(Ta=25°C)

Characteristics	Symbol	Ratings	Unit
Drain-source voltage	VDSS	60	V
Gate-source voltage	VGSS	±20	V
Drain Current (DC)	ID	0.1	A

* For Reference

WAFER PROBING SPEC (Ta=25°C)

No	MODE	LIMIT				CONDITIONS
		MIN.	Typ	MAX.	UNIT	
1	IGSS			±10	uA	VGS= ±20V VDS= 0V
2	IDSS			1	uA	VDS= 60V VGS= 0V
3	BVDSS	60			V	ID= 10uA
4	VTH	0.8	1	1.48	V	ID= 250uA VDS=VGS
5	RDS(on)1		3.2	4.2	Ω	ID= 220mA VGS= 10V
6	RDS(on)2		3.7	4.8	Ω	ID= 220mA VGS= 4.5V
7	VSD	0.5		1.1	V	I= 115mA VGS= 0V

※ Built-in ZD between Gate and Source.

NOTE: